

isc N-Channel MOSFET Transistor

BUK444-500A/B

DESCRIPTION

- Drain Source Voltage
 : V_{DSS}= 500V(Min)
- Low RDS(ON)
- Fast Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

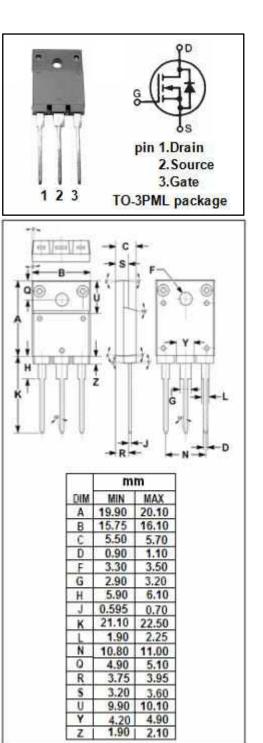
• Designed for Switched Mode Power Supplies (SMPS), motor control,welding, and in general purpose switching resistance applications

ADSOLUTE WAATWOW RATINGS (Ta-25 C)								
	VALUE	UNIT						
Drain-Source Voltage (V _{GS} =0)		500	V					
Gate-Source Voltage		±30 V						
Drain	BUK444-500A	2.1	А					
s@ TC=25℃	BUK444-500B	1.9	A					
Total Dissipation@TC=25℃		25	W					
Max. Operating Junction Temperature		150	°C					
Storage Temperature Range		-55-150	°C					
	ARAMETER Drain-Source Voltag Gate-Source Voltag Drain Current-continuou s@ TC=25°C Total Dissipation@ ⁻¹ Max. Operating Jur	ARAMETER Drain-Source Voltage (V _{GS} =0) Gate-Source Voltage Drain Current-continuou s@ TC=25°C BUK444-500A BUK444-500B Total Dissipation@TC=25°C Max. Operating Junction Temperature	ARAMETERVALUEDrain-Source Voltage (VGS=0)500Gate-Source Voltage±30Drain Current-continuou s@ TC=25°CBUK444-500A2.1BUK444-500B1.9Total Dissipation@TC=25°C25Max. Operating Junction Temperature150					

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	5	°C/W



isc website: <u>www.iscsemi.com</u>

¹ *isc & iscsemi* is registered trademark



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BUK444-500A/B

ELECTRICAL CHARACTERISTICS (Tc=25°C)

SYMBOL	PARAMETER	CONDITIONS		MIN	МАХ	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 0.25mA		500		V
$V_{GS(th)}$	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D = 1.0mA		2.1	4.0	V
R _{DS(on)}	Drain-Source On-stage Resistance	V _{GS} = 10V; I _D = 1.2A	BUK444-500A		2.3	Ω
			BUK444-500B		2.8	Ω
lgss	Gate Source Leakage Current	V _{GS} = ±30V;V _{DS} =0			±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 500V; V _{GS} = 0			20	uA
V _{SD}	Forward On-Voltage	I _S = 2.1A; V _{GS} = 0			1.3	V

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